

Physico-Chemical nanomaterials science.

The properties of Fe-Bi-Pt films obtained by ion-plasma sputtering

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Significant interest in studying of FePt and FeBi alloys conditioned by a manifestation of high coercivity and residual magnetization, which is typical for high magnetic materials [1]. Studies was carried out on thin films, with compositions (at.%): Fe₆₄Pt₂₀Bi₁₆ (composition 1); Fe₇₁Pt₂₀Bi₉ (2); Fe₈₀Pt₁₁Bi₉ (3); Fe₇₁Pt₂₀Bi₉ (4-5). Films with thicknesses about $d \sim 150 - 65$ nm was obtained by a modernized three-electrode ion-plasma sputtering [2] under various deposition conditions.

In the FePtBi films as shown X-ray studies, in the initial state there are a mixture of the nanocrystalline phase (with CSR size $L \sim 2.1-2.2$ nm) and traces of PbBi₂ phase. After heat treatment in vacuum at a temperature of 770-780 K we saw fcc FePt ($a=0.3724-0.3707$ nm), PbBi₂ phase and traces of FeO.

The FePtBi films (composition 3-4) are characterized by anisotropy of magnetic properties. In the perpendicular magnetic field orientation, the films are showing the weak hysteresis properties. The coercivity does not exceed 0.16 kA/m in the initial state in parallel fields. The decomposition of NCP after heat treatment at 770 K and formation supersaturated solid solution of FePt leads to an increase in coercivity up to 11 kA/m. Heating above this temperature leads to the oxidation, which leads to significant deterioration of magnetic properties. Thus, improvement of magnetic characteristics can be realized by choosing holding time at a predetermined temperature. The Fe₈₀Pt₁₁Bi₉ and Fe₈₅Pt₆Bi₉ films are characterized precision value of temperature coefficient of resistance $3-6 \cdot 10^{-5} \text{ K}^{-1}$ in initial state

1. Zhen C., Zhai X., Ma L., Li X., Nie X. Effects of C layer on the microstructure and magnetic properties of FePt recording media films // Materials Science and Engineering B -2006.-**129**. P. 261–264
2. Bashev V.F., Dotshenko F.F. Miroshnichenko I.S. Pasalsky V.H. Structure and electrical properties of Ag–W films in metastable states. // The Physics of

